



Design Example Report

| | |
|------------------------|--|
| Title | <i>3.0 W Charger using LNK363P</i> |
| Specification | Input: 85 – 265 VAC Output: 5.0V / 600 mA |
| Application | Cell Phone Charger |
| Author | Power Integrations Applications Department |
| Document Number | DER-62 |
| Date | August 24, 2005 |
| Revision | 1.0 |

Summary and Features

- Low cost CV/CC cell phone charger
- No Load consumption less than 300 mW
- Meets CEC efficiency and no-load specification

The products and applications illustrated herein (including circuits external to the products and transformer construction) may be covered by one or more U.S. and foreign patents or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com.

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Important Note:

Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.

Design Reports contain a power supply design specification, schematic, bill of materials, and transformer documentation. Performance data and typical operation characteristics are included. Typically only a single prototype has been built.



1 Introduction

This document is an engineering prototype report describing a 3.0 W power supply utilizing a LNK363P. This power supply is intended as a cell phone charger evaluation platform. Power Integrations E-shield technology of transformer construction allows this design to meet EMI requirement without using a common mode choke.

The document contains the power supply specification, schematic, bill of materials, transformer documentation.

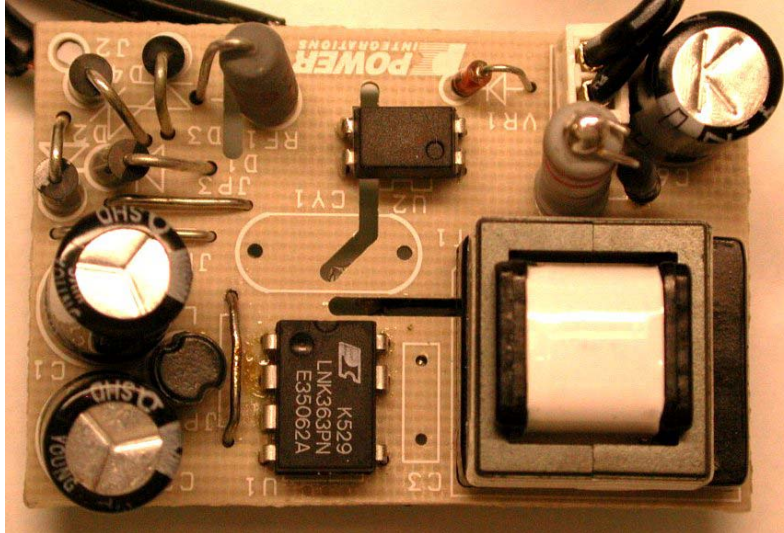


Figure 1 – Populated circuit board – Top view

2 Power Supply Specification

| Description | Symbol | Min | Typ | Max | Units | Comment |
|-------------------------------|---------------|--|-------|------|-------|-----------------------------|
| Input | | | | | | |
| Voltage | V_{IN} | 85 | | 265 | VAC | 2 Wire – no P.E. |
| Frequency | f_{LINE} | 47 | 50/60 | 64 | Hz | |
| No-load Input Power (230 VAC) | | | | 0.5 | W | |
| Output | | | | | | 20 MHz Bandwidth |
| Output Voltage 1 | V_{OUT1} | 4.75 | 5.0 | 5.75 | V | |
| Output Ripple Voltage 1 | $V_{RIPPLE1}$ | | 60 | | mV | |
| Output Current 1 | I_{OUT1} | 534 | 600 | 666 | mA | |
| Total Output Power | | | | | | |
| Continuous Output Power | P_{OUT} | | 3.0 | | W | |
| Efficiency | η | 59 | | | % | typical at full load, 25 °C |
| Environmental | | | | | | |
| Conducted EMI | | Meets CISPR22B / EN55022B | | | | |
| Safety | | Designed to meet IEC950, UL1950 Class II | | | | |
| Ambient Temperature | T_{AMB} | 0 | | 50 | °C | Free convection, sea level |

3 Schematic

3.1 With RCD clamp

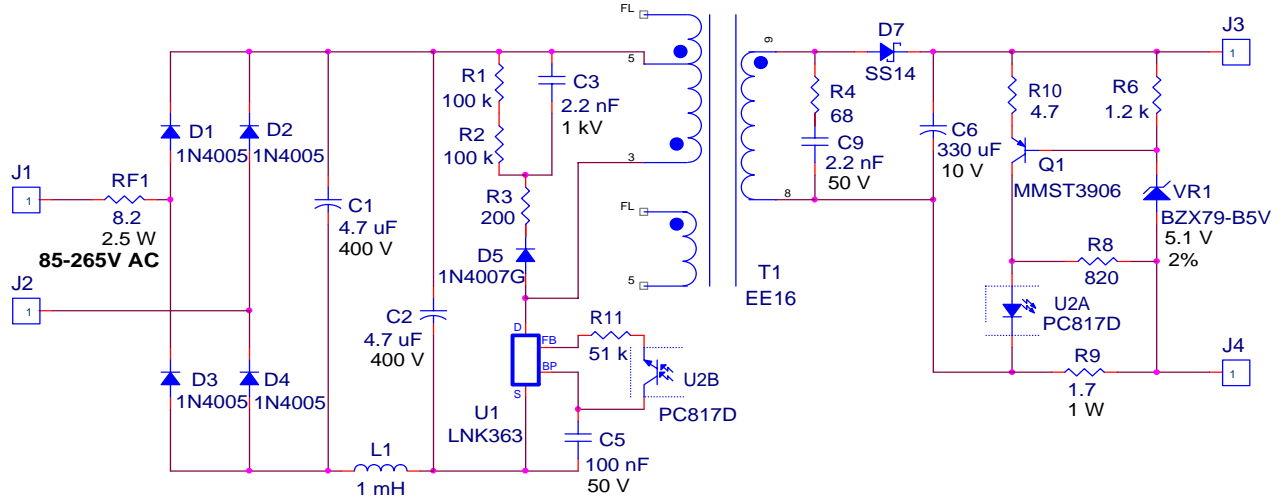


Figure 2 – Schematic with RCD clamp.

3.2 With Zener clamp and bias winding

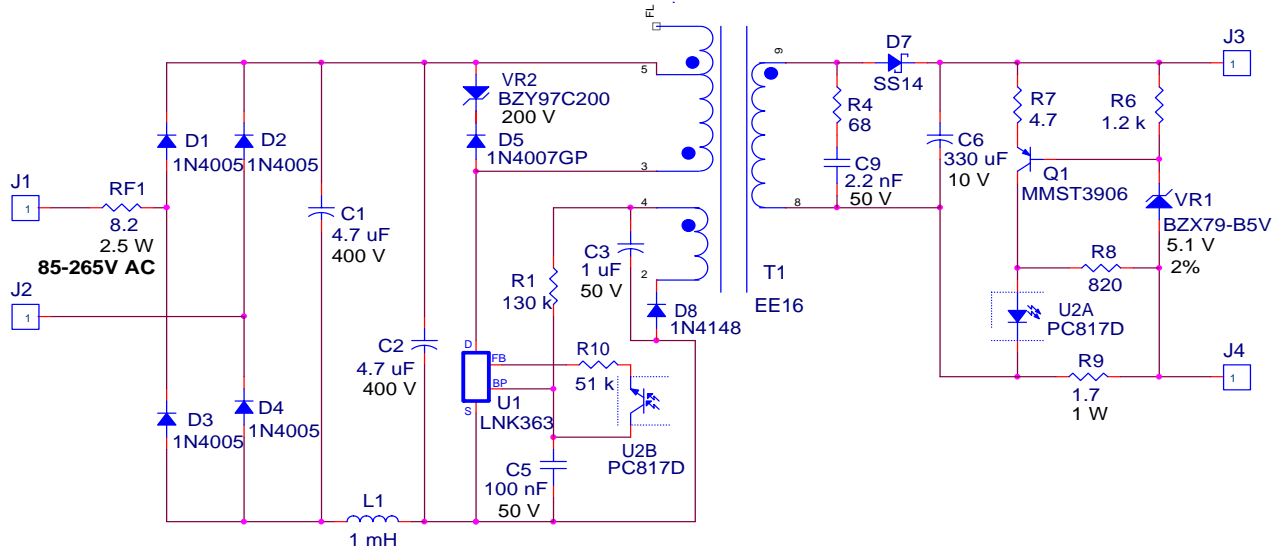


Figure 3 - Schematic with zener clamp and bias winding.



4 PCB

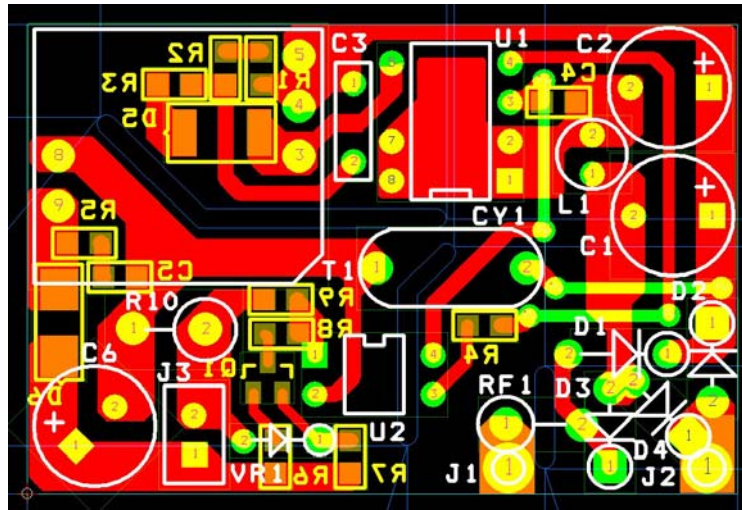


Figure 4 – Printed circuit board

5 Bill Of Materials—RCD clamp

| Item | Qty | Value | Description | Ref |
|------|-----|------------|---|-------------|
| 1 | 2 | 4.7 uF | 4.7 uF, 400 V, Electrolytic, (8 x 11.5) | C1 C2 |
| 2 | 1 | 2.2 nF | 2.2 nF, 1 kV, Disc Ceramic | C3 |
| 3 | 1 | 100 nF | 100 nF, 50 V, Ceramic, X7R, 0805 | C5 |
| 4 | 1 | 330 uF | 330 uF, 10 V, Electrolytic, Low ESR, 180 mOhm | C6 |
| 5 | 1 | 2.2 nF | 2.2 nF, 50 V, Ceramic, X7R, 0805 | C9 |
| 6 | 4 | 1N4005 | 600 V, 1 A, Rectifier, DO-41 | D1 D2 D3 D4 |
| 7 | 1 | 1N4007G | 1000 V, 1 A, Rectifier, Glass Passivated, 2 us, DO-41 | D5 |
| 8 | 1 | SS14 | 40 V, 1 A, Schottky, DO-214AC | D7 |
| 13 | 1 | 1 mH | 1 mH, 0.15 A, Ferrite Core | L1 |
| 14 | 1 | MMST3906 | PNP, Small Signal BJT, 40 V, 0.2 A, SOT-323 | Q1 |
| 15 | 2 | 100 k | 100 k, 5%, 1/4 W, Metal Film, 1206 | R1 R2 |
| 16 | 1 | 200 | 200 R, 5%, 1/8 W, Metal Film, 0805 | R3 |
| 17 | 1 | 68 | 68 R, 5%, 1/8 W, Metal Film, 0805 | R4 |
| 18 | 1 | 1.2 k | 1.0k 5%, 1/8 W, Metal Film, 0805 | R6 |
| 19 | 1 | 820 | 820 R, 5%, 1/8 W, Metal Film, 0805 | R8 |
| 20 | 1 | 1.7 | 1.7 R, 5%, 1 W, Metal Oxide | R9 |
| 21 | 1 | 8.2 | 8.2 R, 2.5 W, Fusible/Flame Proof Wire Wound | RF1 |
| 22 | 1 | 4.7 | 4.7 R, 5% Metal film 0805 | R10 |
| 23 | 1 | 51 k | 51 k, 5% Metal film 0805 | R11 |
| 24 | 1 | EE16 | Bobbin, EE16 Horizontal, 10 Pins | T1 |
| 25 | 1 | LNK363P | PI's device | U1 |
| 26 | 1 | PC817D | Opto coupler, 35 V, CTR 300-600%, 4-DIP | U2 |
| 27 | 1 | BZX79-B5V1 | 5.1 V, 500 mW, 2%, DO-35 | VR1 |



6 Transformer Specification

6.1 Electrical Diagram

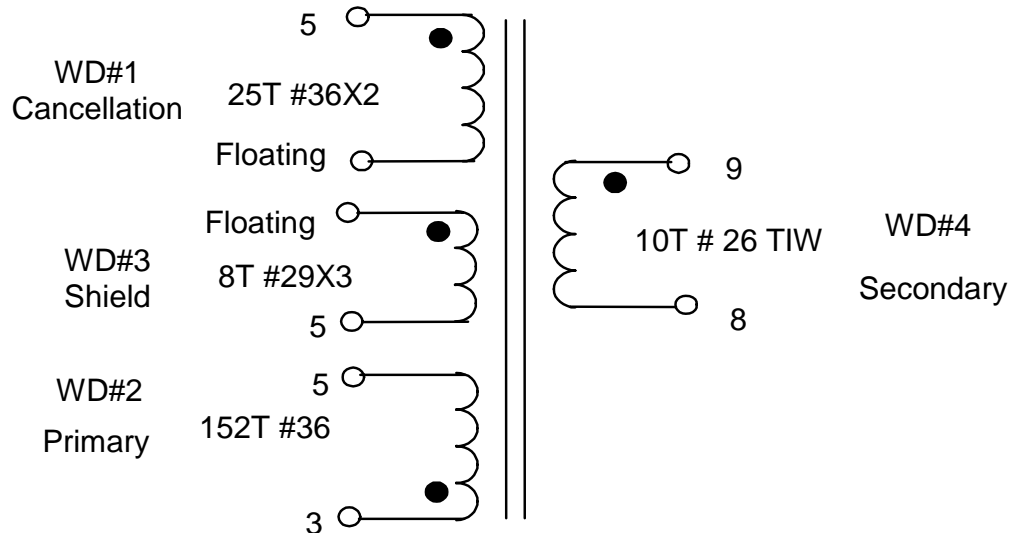


Figure 5 – Transformer Electrical Diagram

6.2 Electrical Specifications

| | | |
|---|--|------------------------------|
| Electrical Strength | 60Hz 1minute, from Pins 1-5 to Pins 6-10 | 3000 V ac |
| Primary Inductance (Pin 3 to Pin 5) | All windings open | 1940 uH +/- 5% at 132 KHz |
| Resonant Frequency. (Pin 3 to Pin 5) | All windings open | 700 kHz (Min.) |
| Primary Leakage Inductance. (Pin 3 to Pin 5) | Pins 9-8 shorted | 110 uH Max. |

6.3 Materials

| Item | Description |
|------|---|
| [1] | Core: PC40EE16-Z, TDK or equivalent Gapped for AL of 84 nH/T ² |
| [2] | Bobbin: Horizontal 10 pin |
| [3] | Magnet Wire: #36AWG |
| [4] | Magnet Wire: #29 AWG |
| [5] | Triple Insulated Wire: #26 AWG. |
| [6] | Tape: 3M 1298 Polyester Film, 2.0 mils thick, 8.2 mm wide |
| [7] | Varnish |

6.4 Transformer Build Diagram

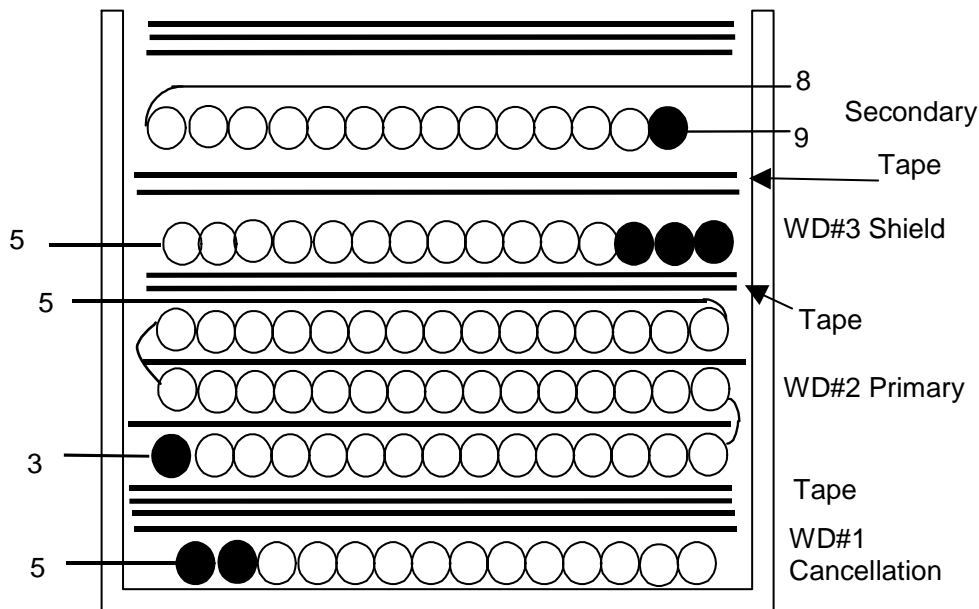


Figure 6 – Transformer Build Diagram

6.5 Transformer Construction

| | |
|-----------------------------|--|
| WD1 Cancellation Winding | Primary pin side of the bobbin oriented to left hand side. Start at Pin 5. Wind 25 bifilar turns of item [8] from right to left. Wind with tight tension across entire bobbin evenly. Cut at the end. |
| Insulation | 4 Layers of tape [6] for insulation. |
| WD#2 Primary winding | Start at pin 3 wind 51 turns of item [3] from left to right. Apply 1 layer tape of [6]. Then wind another 50 turns next layer from right to left. Apply 1 layer tape of [6]. Wind the rest 51 turns in third layer from left to right. Wind with tight tension across entire bobbin evenly Finish at pin 5 |
| Insulation | 2 Layers of tape [6] for insulation. |
| WD #3 Shield Winding | Start at Pin 8 temporarily, wind 8 Trifilar turns of item [4]. Wind from right to left with tight tension. Wind uniformly, in a single layer across entire width of bobbin. Finish at pin5. Cut at the start lead. |
| Insulation | 2 Layers of tape [6] for insulation. |
| WD #4 Secondary Winding | Start at pin 9, wind 10 turns of item [5] from right to left. Wind uniformly, in a single layer across entire bobbin evenly. Finish on pin 8. |
| Outer Insulation | 3 Layers of tape [6] for insulation. |
| Core Assembly | Assemble and secure core halves. |
| Varnish | Varnish |



7 Transformer Spreadsheets

| ACDC_LinkSwitch-XT_063005; Rev.0.2; Copyright Power Integrations 2005 | INPUT | INFO | OUTP UT | UNIT | ACDC_LinkSwitch-XT_063005_Rev0-2.xls; LinkSwitch-XT Continuous/Discontinuous Flyback Transformer Design Spreadsheet |
|---|--------|-------------|--------------|-------------------|---|
| ENTER APPLICATION VARIABLES | | | | | |
| VACMIN | 85 | | | Volts | Minimum AC Input Voltage |
| VACMAX | 265 | | | Volts | Maximum AC Input Voltage |
| fL | 50 | | | Hertz | AC Mains Frequency |
| VO | 5.00 | | | Volts | Output Voltage (main) |
| IO | 0.60 | | | Amps | Power Supply Output Current |
| CC Threshold Voltage | 1.00 | | | Volts | Voltage drop across sense resistor. For CV only circuits enter "0" |
| PO | | | 3.6 | Watts | Output Power (VO x IO + CC dissipation) |
| n | 0.60 | | | | Efficiency Estimate at output terminals. For CV only designs enter 0.7 if no better data available |
| Z | 0.75 | | 0.75 | | Loss Allocation Factor (suggest 0.5 for CC=0 V, 0.75 for CC=1 V) |
| tC | 2.90 | | | mSec onds | Bridge Rectifier Conduction Time Estimate |
| CIN | 9.40 | | | uFara ds | Input Capacitance |
| ENTER LinkSwitch-HF VARIABLES | | | | | |
| LinkSwitch-XT | LNK363 | | | Univer sal | 115 Doubled/230V |
| Chosen Device | | LNK363 | Power Out | 10 W | 10 W |
| ILIMITMIN | | | 0.195 | Amps | Minimum Current Limit |
| ILIMITMAX | | | 0.225 | Amps | Maximum Current Limit |
| fSmin | | | 12400 | Hertz | Minimum Device Switching Frequency |
| I ² fmin | | | 5471.7 | Hertz | I ² f (product of current limit squared and frequency is trimmed for tighter tolerance) |
| VOR | 99.00 | | 99 | Volts | Reflected Output Voltage |
| VDS | | | 10 | Volts | LinkSwitch-HF on-state Drain to Source Voltage |
| VD | | | 0.5 | Volts | Output Winding Diode Forward Voltage Drop |
| KP | | | 0.90 | | Ripple to Peak Current Ratio (0.6<KRP<1.0 : 1.0<KDP<6.0) |
| ENTER TRANSFORMER CORE/CONSTRUCTION VARIABLES | | | | | |
| Core Type | | | EE16 | | Suggested smallest commonly available core |
| Core | | EE16 | | P/N: | PC40EE16-Z |
| Bobbin | | EE16_BOBBIN | | P/N: | EE16_BOBBIN |
| AE | | | 0.192 | cm ² | Core Effective Cross Sectional Area |
| LE | | | 3.5 | cm | Core Effective Path Length |
| AL | | | 1140 | nH/T ² | Ungapped Core Effective Inductance |
| BW | | | 8.6 | mm | Bobbin Physical Winding Width |
| M | | | 0 | mm | Safety Margin Width (Half the Primary to Secondary Creepage Distance) |
| L | | | 3 | | Number of Primary Layers |
| NS | 10 | | 10 | | Number of Secondary Turns |
| DC INPUT VOLTAGE PARAMETERS | | | | | |
| VMIN | | | 83 | Volts | Minimum DC Input Voltage |
| VMAX | | | 375 | Volts | Maximum DC Input Voltage |
| CURRENT WAVEFORM SHAPE PARAMETERS | | | | | |
| DMAX | | | 0.61 | | Maximum Duty Cycle |



| | | | | | |
|---|-------|--|--------|-------------------|--|
| IAVG | | | 0.07 | Amps | Average Primary Current |
| IP | | | 0.1950 | Amps | Minimum Peak Primary Current |
| IR | | | 0.1746 | Amps | Primary Ripple Current |
| IRMS | | | 0.09 | Amps | Primary RMS Current |
| TRANSFORMER PRIMARY DESIGN PARAMETERS | | | | | |
| LP | | | 1942 | uHenries | Typical Primary Inductance. +/- 12% |
| LP_TOLERANCE | 12.00 | | 12 | % | Primary inductance tolerance |
| NP | | | 152 | | Primary Winding Number of Turns |
| ALG | | | 84 | nH/T ² | Gapped Core Effective Inductance |
| BM | | | 1494 | Gauss | Maximum Operating Flux Density, BM<1500 is recommended |
| BAC | | | 600 | Gauss | AC Flux Density for Core Loss Curves (0.5 X Peak to Peak) |
| ur | | | 1654 | | Relative Permeability of Ungapped Core |
| LG | | | 0.27 | mm | Gap Length (Lg > 0.1 mm) |
| BWE | | | 25.8 | mm | Effective Bobbin Width |
| OD | | | 0.169 | mm | Maximum Primary Wire Diameter including insulation |
| INS | | | 0.04 | mm | Estimated Total Insulation Thickness (= 2 * film thickness) |
| DIA | | | 0.132 | mm | Bare conductor diameter |
| AWG | | | 36 | AWG | Primary Wire Gauge (Rounded to next smaller standard AWG value) |
| CM | | | 25 | Cmils | Bare conductor effective area in circular mils |
| CMA | | | 286 | Cmils/Amp | Primary Winding Current Capacity (200 < CMA < 500) |
| TRANSFORMER SECONDARY DESIGN PARAMETERS | | | | | |
| Lumped parameters | | | | | |
| ISP | | | 2.97 | Amps | Peak Secondary Current |
| ISRMS | | | 1.16 | Amps | Secondary RMS Current |
| IRIPPLE | | | 0.99 | Amps | Output Capacitor RMS Ripple Current |
| CMS | | | 232 | Cmils | Secondary Bare Conductor minimum circular mils |
| AWGS | | | 26 | AWG | Secondary Wire Gauge (Rounded up to next larger standard AWG value) |
| DIAS | | | 0.41 | mm | Secondary Minimum Bare Conductor Diameter |
| ODS | | | 0.86 | mm | Secondary Maximum Outside Diameter for Triple Insulated Wire |
| INSS | | | 0.23 | mm | Maximum Secondary Insulation Wall Thickness |
| VOLTAGE STRESS PARAMETERS | | | | | |
| VDRAIN | | | 603 | Volts | Maximum Drain Voltage Estimate (Includes Effect of Leakage Inductance) |
| PIVS | | | 30 | Volts | Output Rectifier Maximum Peak Inverse Voltage |
| TRANSFORMER SECONDARY DESIGN PARAMETERS (MULTIPLE OUTPUTS) | | | | | |
| 1st output | | | | | |
| VO1 | 5.50 | | 5.5 | Volts | Main Output Voltage (if unused, defaults to single output design) |
| IO1 | 0.60 | | 0.600 | Amps | Output DC Current |
| PO1 | | | 3.30 | Watts | Output Power |
| VD1 | | | 0.500 | Volts | Output Diode Forward Voltage Drop |
| NS1 | | | 10.91 | | Output Winding Number of Turns |
| ISRMS1 | | | 1.160 | Amps | Output Winding RMS Current |
| IRIPPLE1 | | | 0.99 | Amps | Output Capacitor RMS Ripple Current |
| PIVS1 | | | 32 | Volts | Output Rectifier Maximum Peak Inverse Voltage |
| CMS1 | | | 232 | Cmils | Output Winding Bare Conductor minimum circular mils |
| AWGS1 | | | 26 | AWG | Wire Gauge (Rounded up to next larger standard AWG value) |
| DIAS1 | | | 0.41 | mm | Minimum Bare Conductor Diameter |
| ODS1 | | | 0.79 | mm | Maximum Outside Diameter for Triple Insulated Wire |



8 Performance Data

All measurements performed at room temperature, 60 Hz input frequency. The data were taken at the end of a 6 feet long output cable. The DC resistance of the cable is about 0.2 ohm.

8.1 Efficiency vs CEC

8.1.1 With RCD Clamp, no bias winding

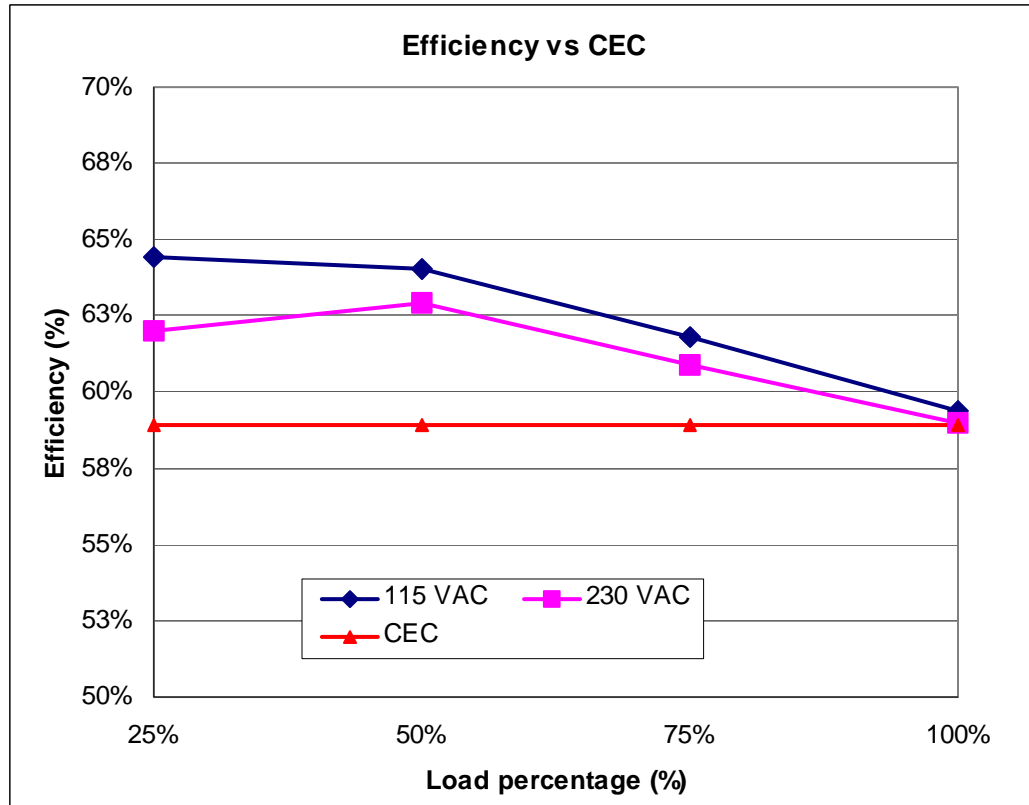


Figure 7 – Efficiency vs load, RCD clamp.

Note the CEC requirement is 58.9%, Tested average efficiency: 115VAC, 62.4%; 230VAC, 61.2%



8.1.2 With Zener Clamp and Bias winding

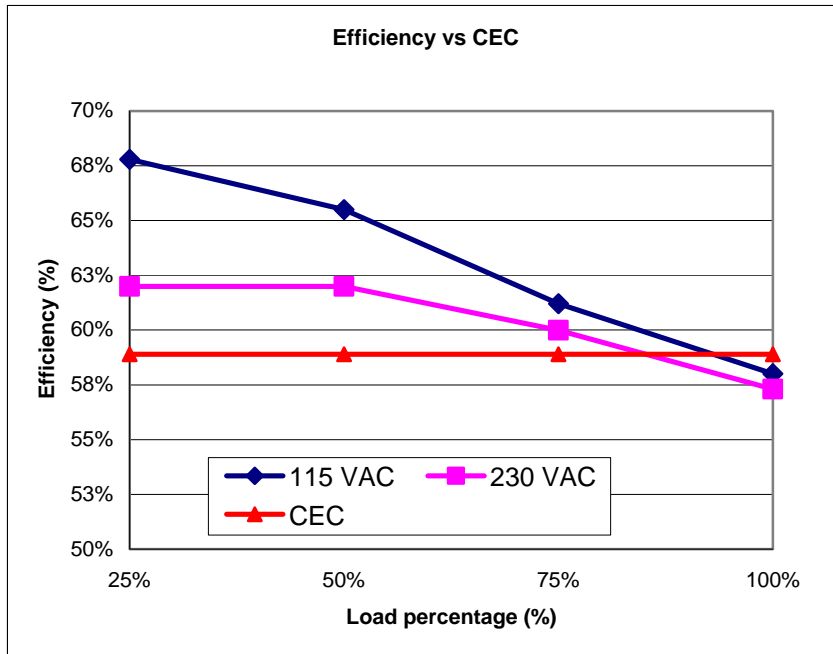


Figure 8 - Efficiency vs output current with Zener clamp and bias winding.

Note the CEC requirement is 58.9%, Tested average efficiency: 115VAC, 62.9%; 230VAC, 60.4%

8.2 Efficiency vs Input Voltage

8.2.1 With RCD clamp, no bias winding

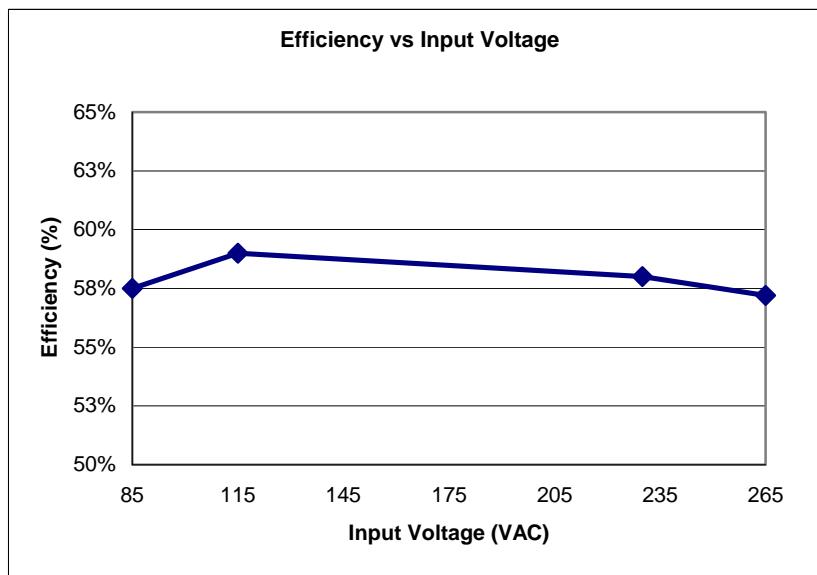


Figure 9 - Efficiency vs input voltage, RCD clamp, no bias winding. Tested at 3.03W output.



8.2.2 With zener clamp and bias winding

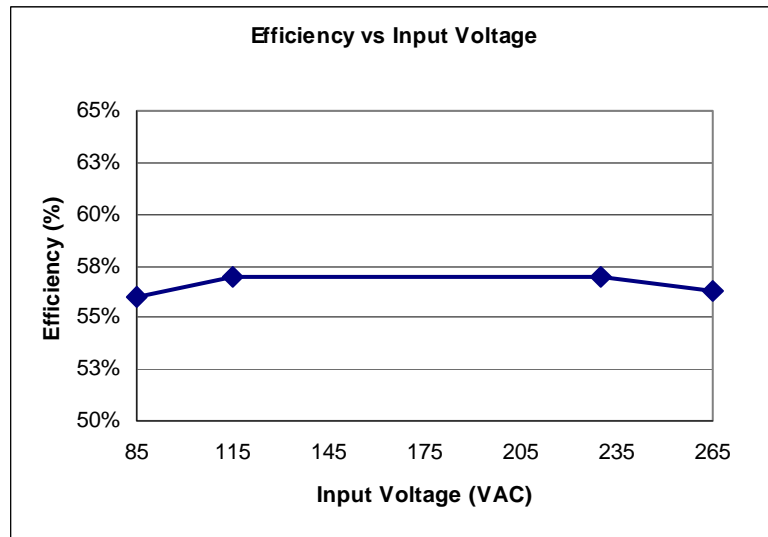


Figure 10 - Full load efficiency vs input voltage, zener clamp and bias winding.

8.3 No-Load Input Power

8.3.1 RCD clamp, no bias winding

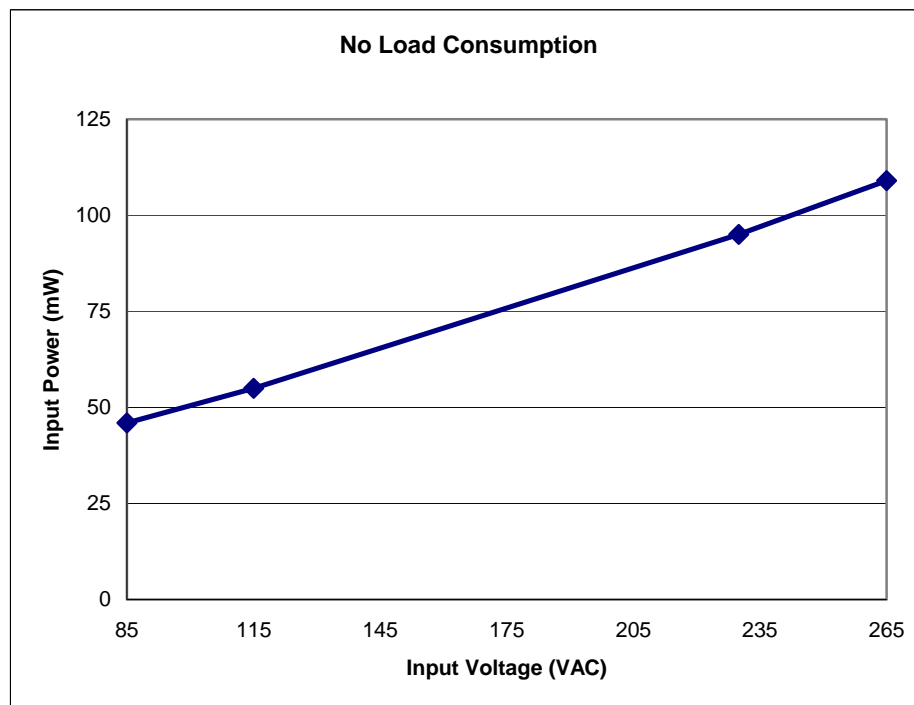


Figure 11 - No load consumption RCD clamp, no bias winding.

Note the CEC requirement is < 500mW



8.3.2 Zener clamp clamp and bias winding

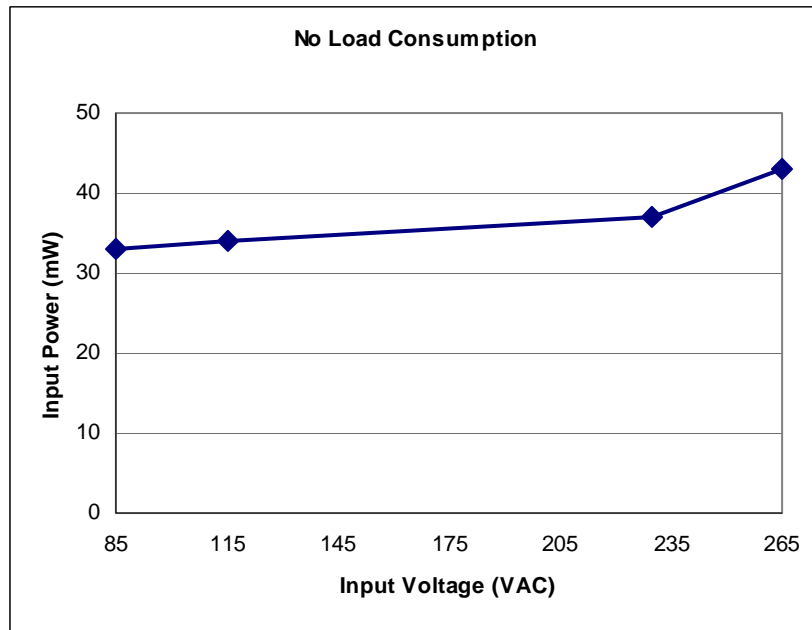


Figure 12 - No load consumption, zener clamp with bias winding.

8.4 Output Regulation

Output characteristic was tested at the end of a 6 feet long output cable. The DC resistance of the cable is about 0.2 ohm.

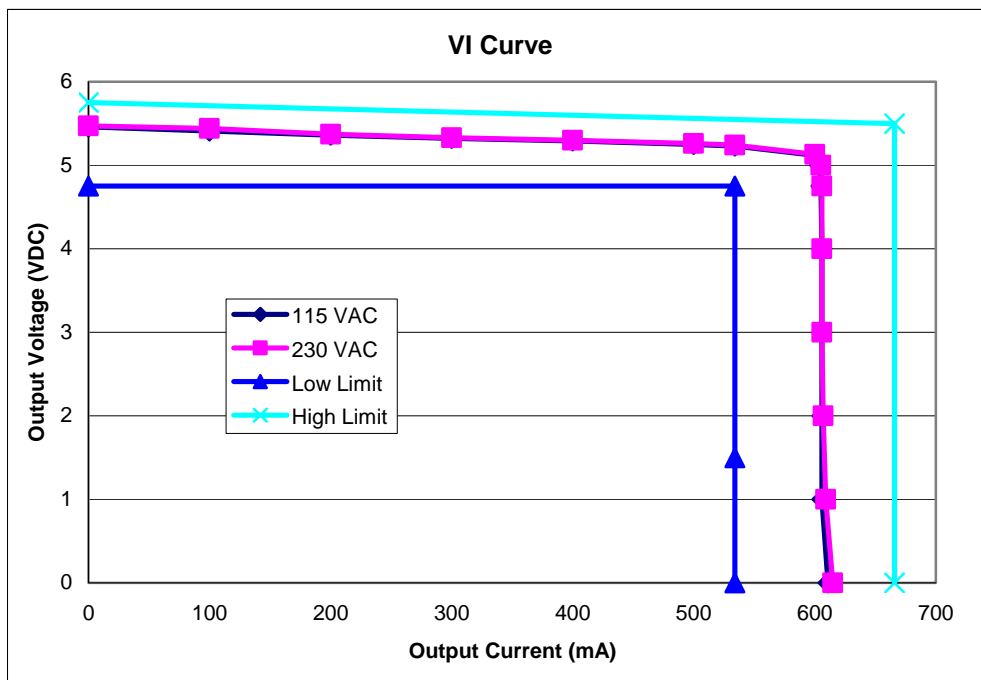


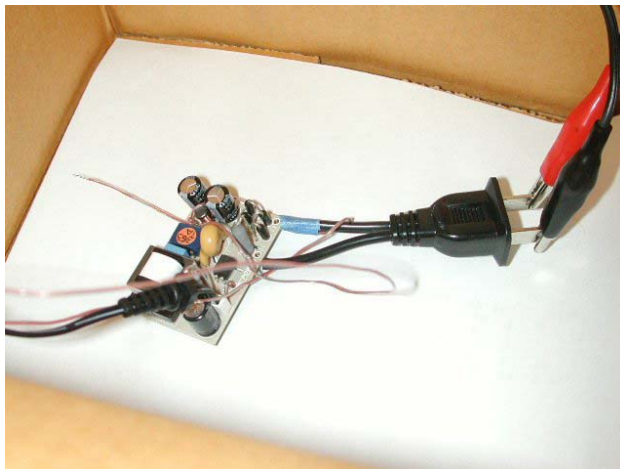
Figure 13 – Output characteristic



8.5 Thermal Performance

Thermal performance was measured inside an enclosure, full load, with no airflow. The ambient thermal probe was about 1 inch away from the device.

8.5.1 Thermal testing set up



8.5.2 Test results of RCD clamp

| Item | 85 VAC | 265 VAC |
|----------------|---------------------------------------|--|
| Ambient | 50°C | 50°C |
| LNK363P | 108°C at 2.82 W output (5.22V, 540mA) | 103°C at 2.84 W output (5.23V, 542mA). |

8.5.3 Thermal performance of Zener clamp and bias winding.

| Item | 85 VAC | 265 VAC |
|----------------|--------------------------------------|---------------------------------------|
| Ambient | 50°C | 50°C |
| LNK363P | 96°C at 2.82 W output (5.22V, 544mA) | 89°C at 2.82 W output (5.22V, 544mA). |



9 Waveforms

9.1 Drain Voltage, Normal Operation

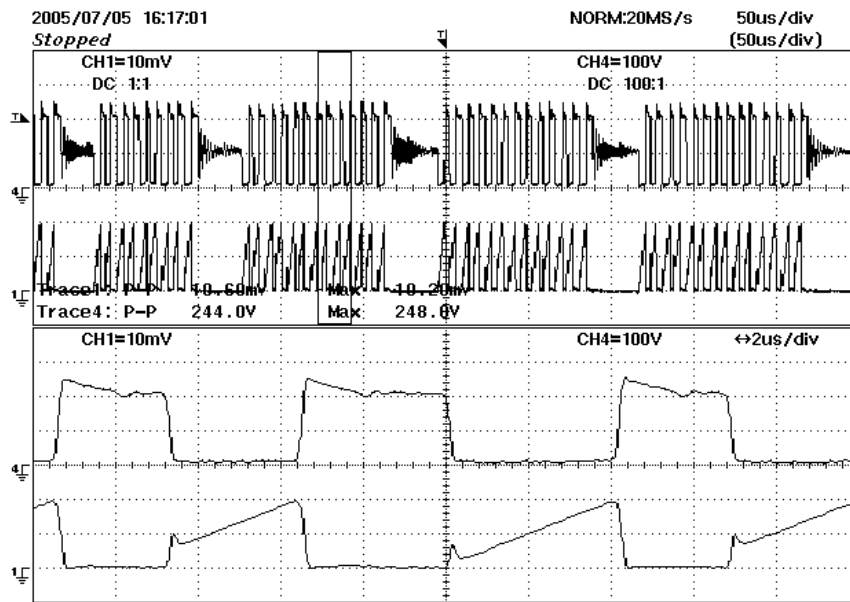


Figure 14 – Drain voltage at 85 VAC input, full load.

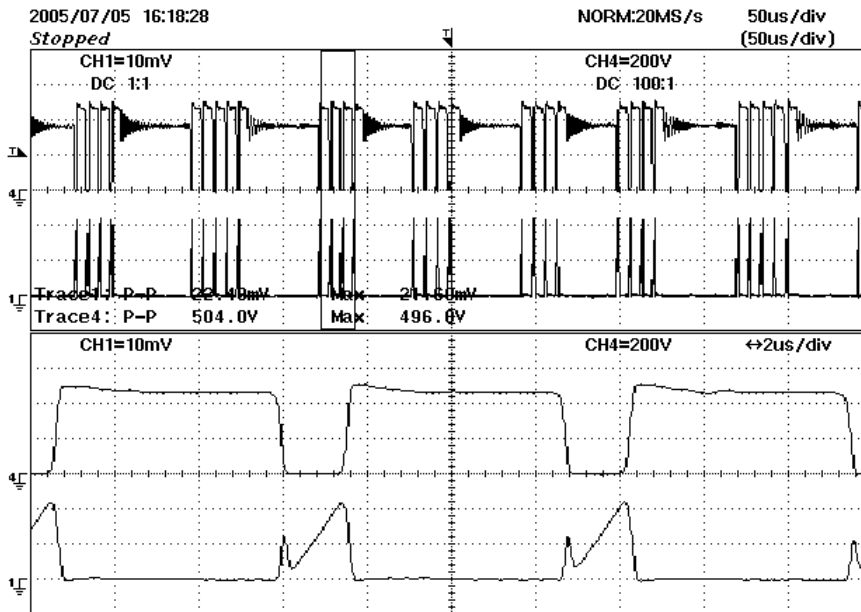


Figure 15 – Drain voltage at 265 VAC, full load.



9.2 Drain Voltage During Startup

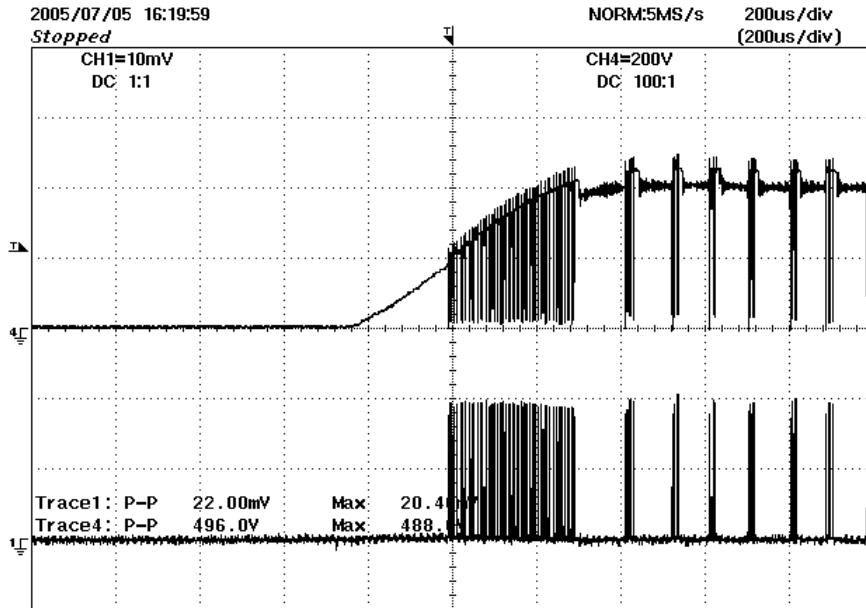


Figure 16 – Drain voltage during startup, 264 VAC, full load.

9.3 Output Voltage Start-up Profile

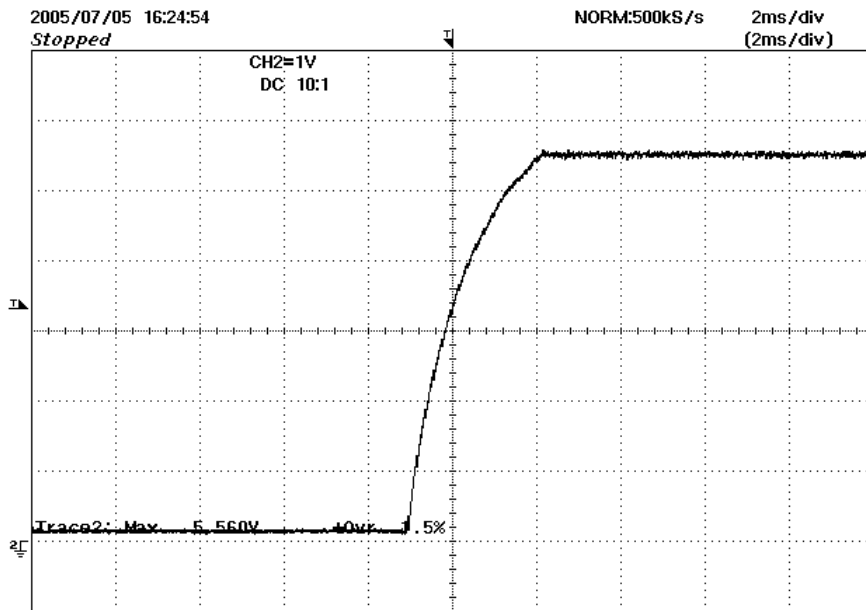


Figure 17 – Output voltage overshoot at 85 VAC, full load.



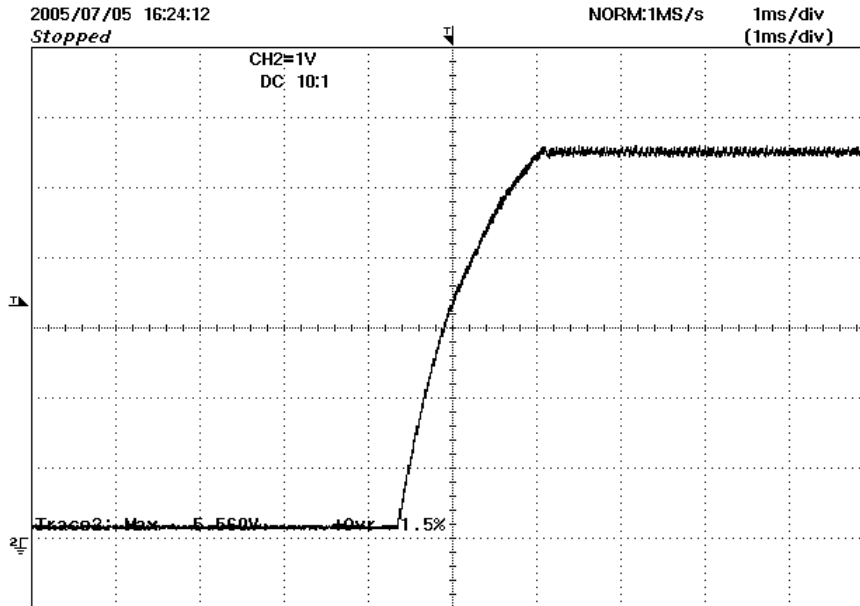


Figure 18 – Output voltage overshoot at 265 VAC, full load.

10 Output Ripple Measurements

10.1.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe must be utilized in order to reduce spurious signals due to pickup. Details of the probe modification are provided in Figure 19 and Figure 20.

The 5125BA probe adapter is affixed with two capacitors tied in parallel across the probe tip. The capacitors include one (1) 0.1 $\mu\text{F}/50\text{ V}$ ceramic type and one (1) 1.0 $\mu\text{F}/50\text{ V}$ aluminum electrolytic. ***The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be maintained (see below).***



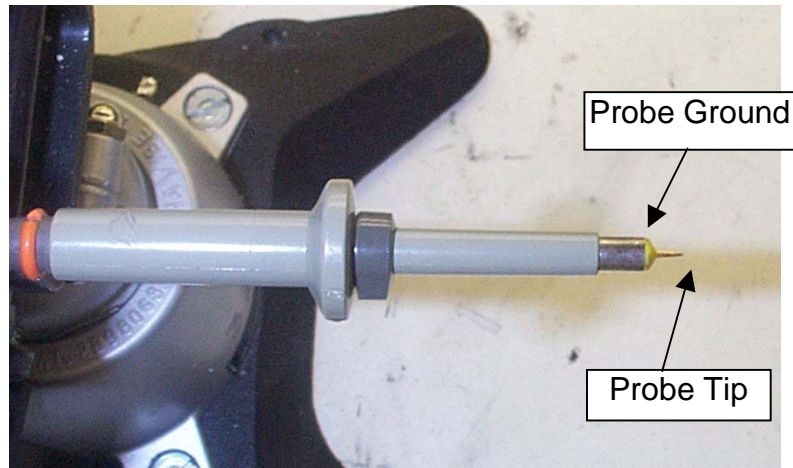


Figure 19 – Oscilloscope Probe Prepared for Ripple Measurement. (End Cap and Ground Lead Removed)

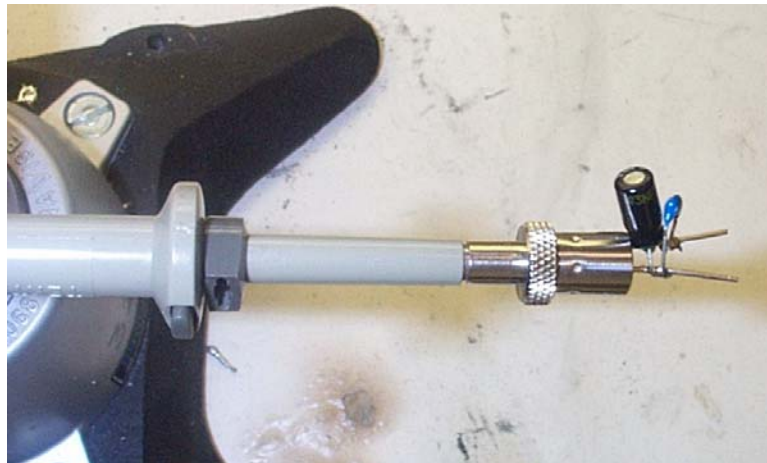


Figure 20 – Oscilloscope Probe with Probe Master 5125BA BNC Adapter. (Modified with wires for probe ground for ripple measurement, and two parallel decoupling capacitors added)

10.1.2 Measurement Results

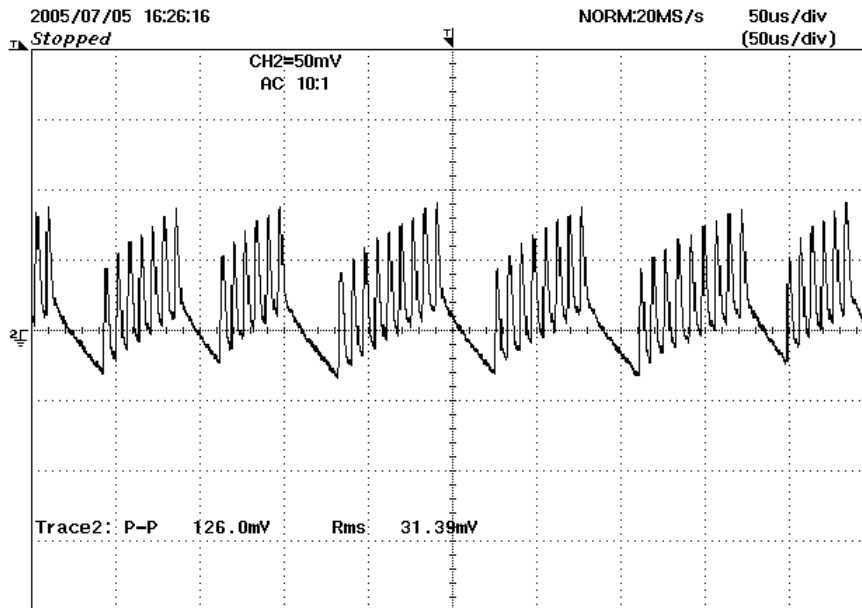


Figure 21 – Output Ripple at 115 VAC, full load.

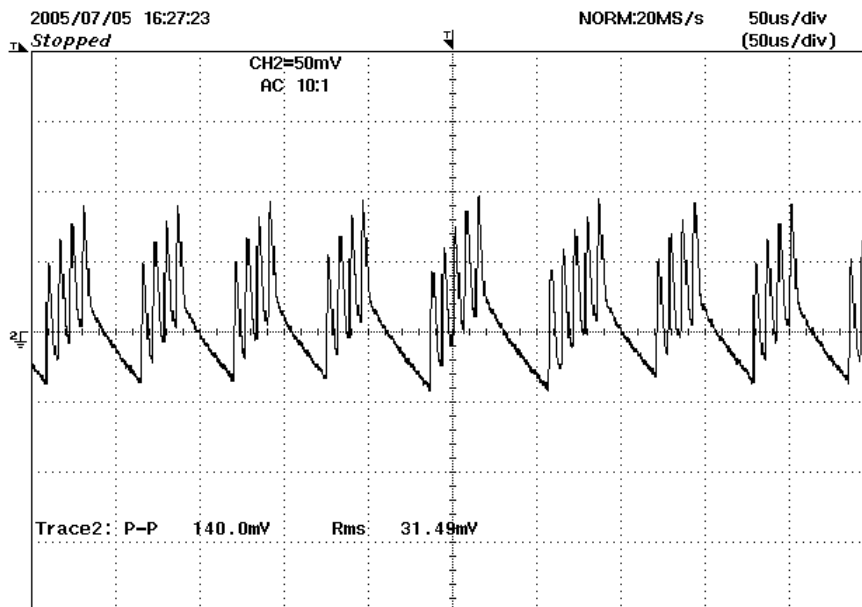
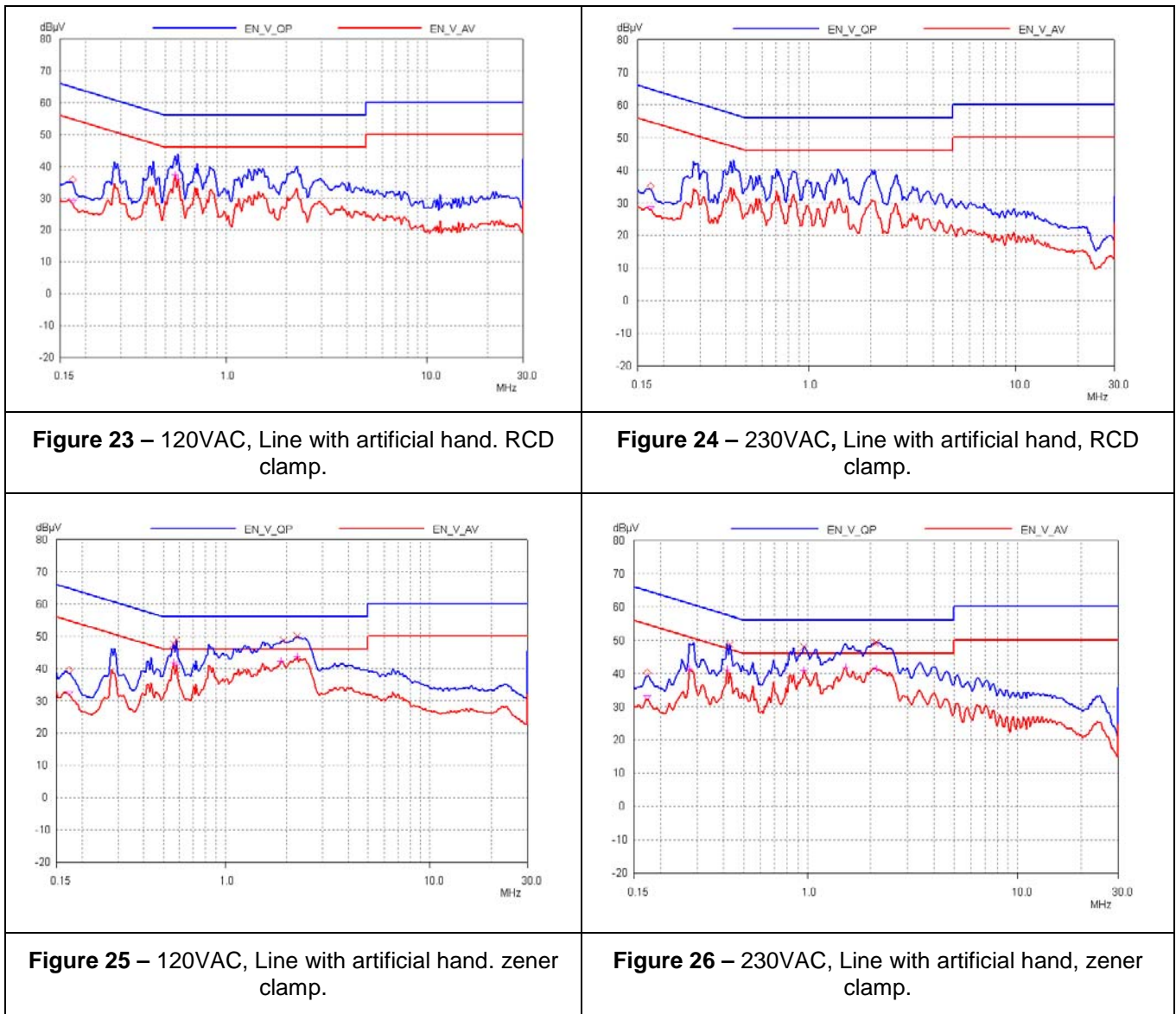


Figure 22 – Output Ripple at 230 VAC input, full load.



11 Conducted EMI

Conducted EMI was tested at full load. The worst case results shown below.



12 Transformer construction with bias winding

12.1 Electrical Diagram

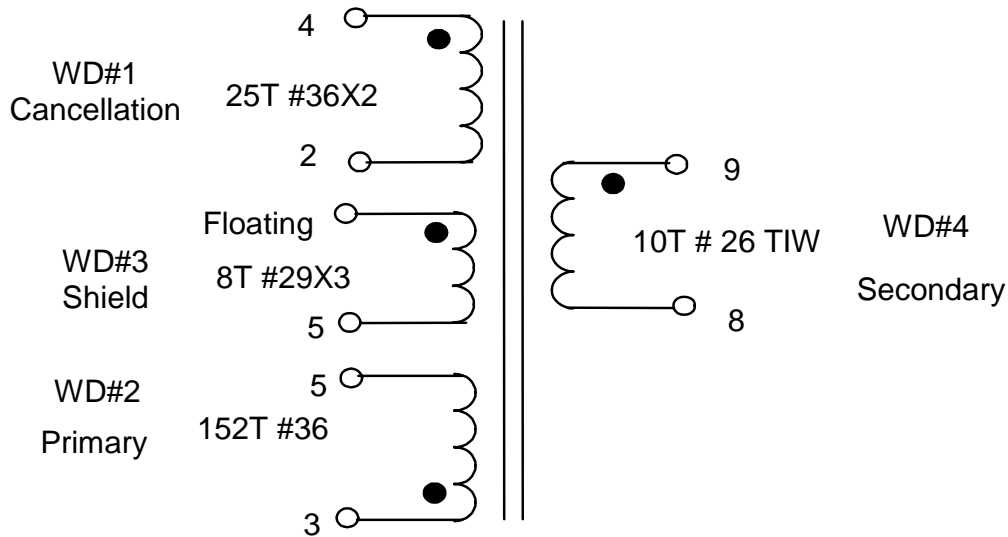


Figure 27 – Transformer Electrical Diagram

12.2 Transformer Build Diagram

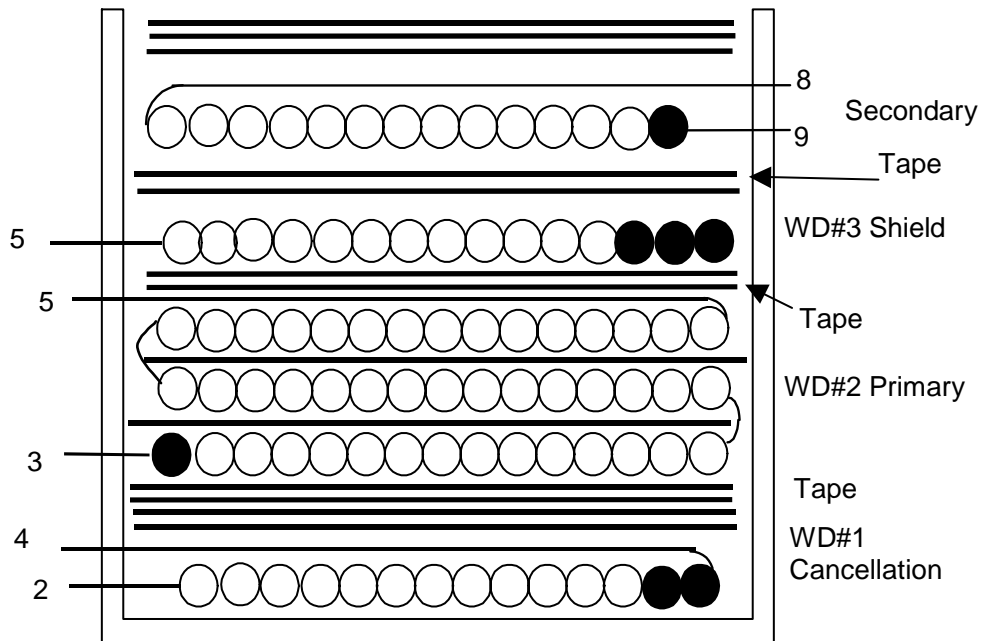


Figure 28 – Transformer Build Diagram

13 Revision History

| Date | Author | Revision | Description & changes | Reviewed |
|-----------------|---------------|-----------------|----------------------------------|-----------------|
| August 24, 2005 | YG | 1.0 | Initial release | AM / VC |



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